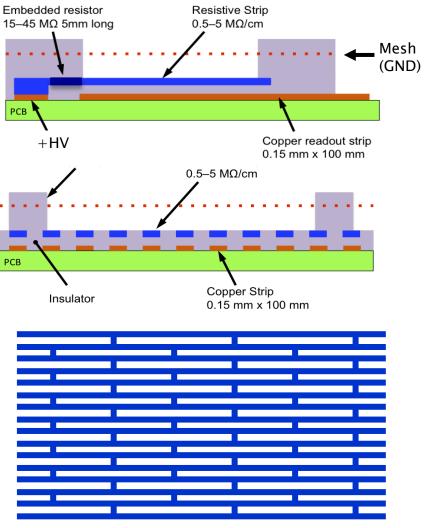
### Carbon sputtering technology for ATLAS MicroMEGAS resistive

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#### 06/02/2014 13th RD51 meeting@ CERN

## **Requirements for ATLAS NSW MM**

- High position resolution for one dimension
  - <100 µm for eta direction. (Resolution of a few cm is allowed for second coordinate.)
- Tolerant for high rate HIP particles
  - $\sim$  5kHz/cm<sup>2</sup>
- Resistive layer should be formed as strips
- Resistivity: ~20MΩ/cm
  - To protect from spark
- Mass production should be available, with large size (1m)
  - ~2000 board should be produced in half year.
- Low cost

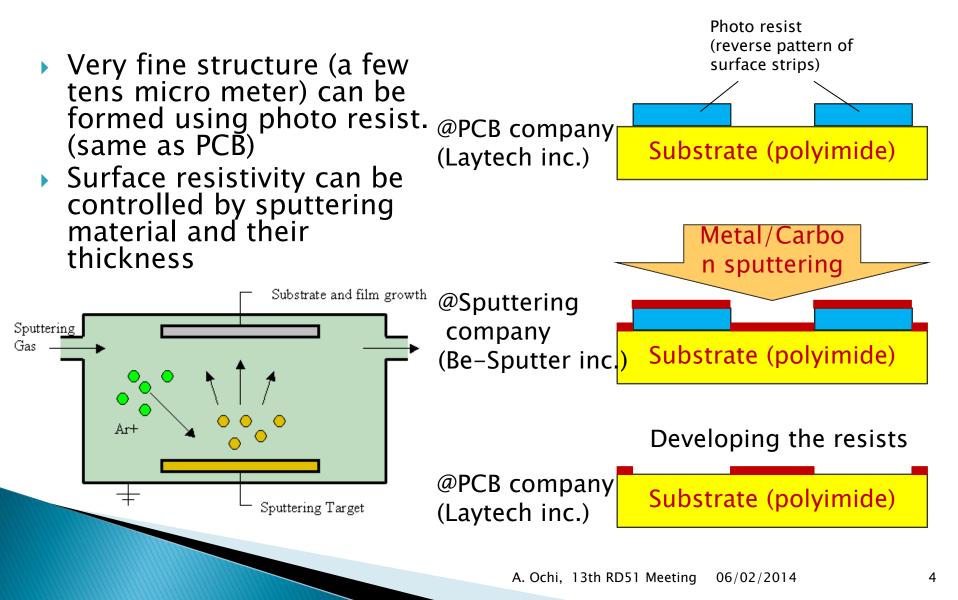


### Two option for resistive electrodes

#### Screen printing

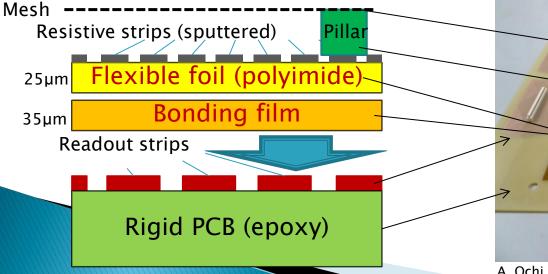
- Already several prototypes (@ CERN and Japan) has been produced.
- Made from carbon loaded polymer.
- Large size (>1m<sup>2</sup>) is available
- 400 µm pitch was available for MAMMA production.
- Carbon sputtering with liftoff process
  - New technique. (Since 2013)
  - Fine pattern (~10µm) is available.
  - Large size (>1m<sup>2</sup>) is available in industrial facilities.
  - Production quality is very well.
    - It is not affected by production environment

# Liftoff process using sputtering



# Prototype of small MicroMEGAS

- June, 2013 bulk MM
  - Surface resistivity:  $10M\Omega/sq$ .
    - With 300Å carbon + 50Å W
- November, 2013 floating mesh
  - Surface resistivity:  $500k\Omega/sq$ .
    - With 3600Å carbon
- The readout board consists of
  - Readout strips (Rigid PCB).
  - Resistive strip foil (Polyimide film).
  - Fine strip pitch of 200 µm is formed on 25µm polyimide foil.
  - Substrate thickness : 60 µm.



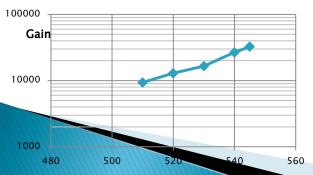


Carbon (300–600Å)

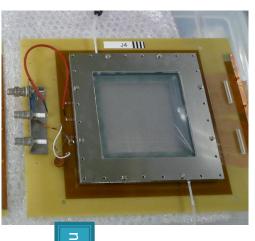
200.00um

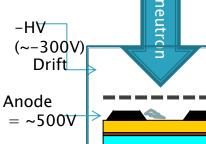
## Fast neutron test

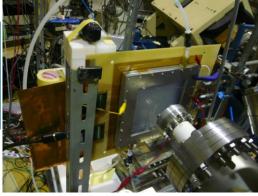
- Beamtests for sputtering MPGD
- Gain curve of 5.9 keV X-ray.
  - Drift = -300V
  - Drift spacing: 5mm
  - Gas: Ar(93%) + CO2(7%)
- Fast Neutron test for spark probability
  - @Kobe Univ.
    - 17-23 Jun. 2013
    - 20-27 Jan. 2014
  - HV current log under intense neutron.
    - Neutron intense : ~ 10<sup>5</sup> cps/cm<sup>2</sup>.
    - 0.01V correspond to 1  $\mu$ A
    - ~600nA of base current was found while beam ON.



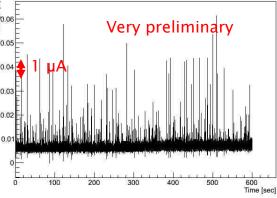








/Users/ochi/Documents/Work/mpgd/J4/current\_monitor/run231708.txt

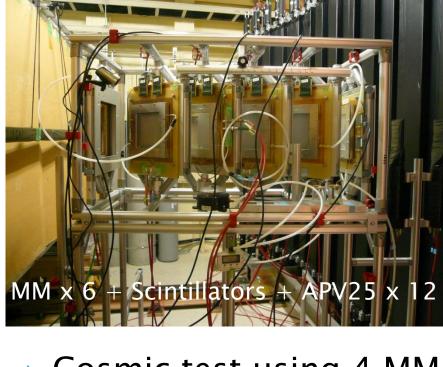


# After sparks by neutrons

No damage is observed on the resistive strips after neutron test



# Charged particle tracking



Cosmic test using 4 MMs<sup>\*\*\*</sup>
 At Kobe Univ, Sept. 2013
 1.4GeV electron beam
 At Spring-8 BL33 beamline,<sup>150</sup>
 Nov. 2013

0.5016

SRS system

# Further improvements and tests for carbon sputtering

- Requirements for carbon strips
  - Resistive control
    - 20  $M\Omega/cm$  is required
      - It correspond to  $600k\Omega/sq$ . for  $300\mu m$  line width.
      - Our first prototype has  $10M\Omega$  /sq.
      - Thicker carbon sputter is required
    - Long time stability of resistivity
      - The resistivity of early prototypes were growing up as time goes on (~2%/day)
      - It was thought that the oxidation of metal (tungsten layer)
      - Is the carbon sputtering without metal layer possible?
  - Mechanical / chemical robustness test
    - Peeling off property (cross cut method)
    - Resistive stability against the bending of the foil
    - Chemical stabilities
      - For alkali and acid, used for PCB process.

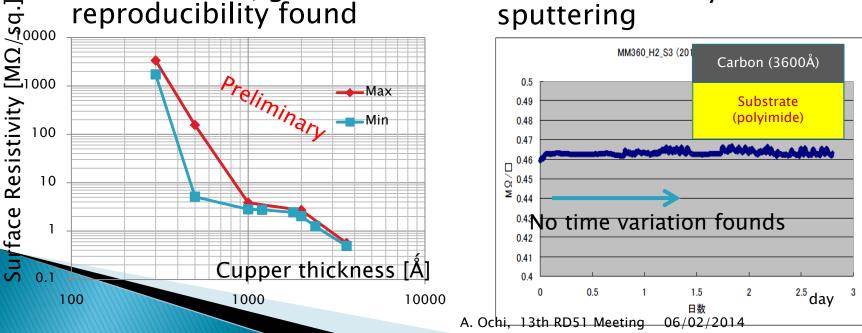
# Resistivity and it's stability

- Resistivity dependence on carbon thickness
  - $300\text{\AA} \rightarrow 2G\Omega/\text{sq}$ .
  - 3600Å → 500kΩ/sq.
  - Conductivity is not proportional to the thickness (t < 1000Å)</li>
  - At t > 1000Å, good reproducibility found

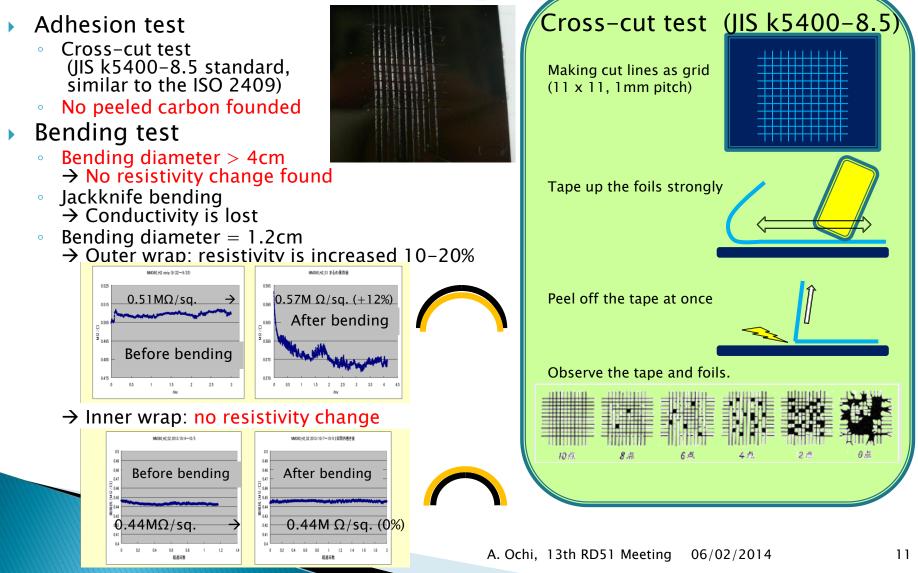
 New prototype: (delivered at September)

- Carbon, 3600Å
- Surface resistivity ~  $500k\Omega/sq$ .
- No time variation founds after several days from sputtering

10

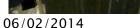


# Mechanical robustness for thick sputtering carbon



# Chemical robustness for new sputtering carbon

- Acid and alkali for PCB processing
  - Hydrochloric acid
  - Nitric acid
  - Sulfuric acid
  - Sodium carbonate
    → No damage on sputtered carbon
  - Sodium hydroxide
    → No damage for short dip
    → Peeling is found after 90 minutes dipping
- Almost all process of PCB production will not affect to the sputtering carbon



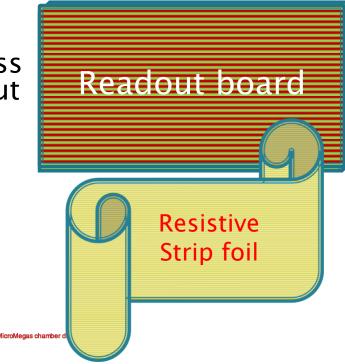
DECAPAGE ALUMINIUM

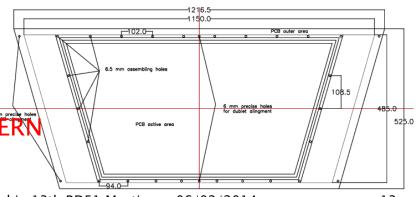
SOUDE CAUSTIQUE

GROUPE BASES

# Prototype of large MMs

- We can divide the production process of resistive strip from that of readout board.
  - Resistive strip is formed on thin foil
  - We don't need fine alignment between resistive strips and readout strips.
- Dividing those processes will make the yield of production growing up.
- We are preparing the large resistive strip foil.
  - Size of foils: 500mm x 1000mm
  - 4 foils are need for a quadruplet
- 8 Foils (4 foils and 4 spare) were delivered to us at 25<sup>th</sup> October.
  - Some basic resistive parameters are checked.
  - Those have been already come to CER





### For patterning process RAYTECH



#### PCB company

- They are expert for FPC (Flexible Printed Circuit) production.
- Liftoff is basic process for FPC production



**Exposure machines** in clean room



**Electro forming machines** 

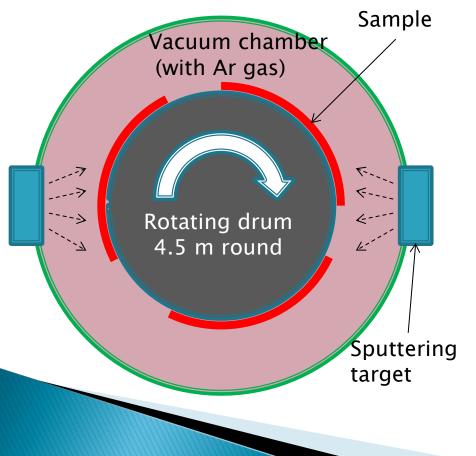


**Etching machines** 

# Sputtering facilities

#### Large size sputtering is available

#### 4.5m x 1m for flexible film





A. Ochi, 13th RD51 Meeting 06/02/2014

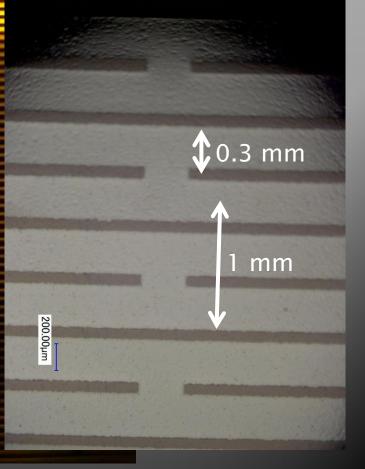
### Large resistive strip foil

866.4mm

#### 425.3mm

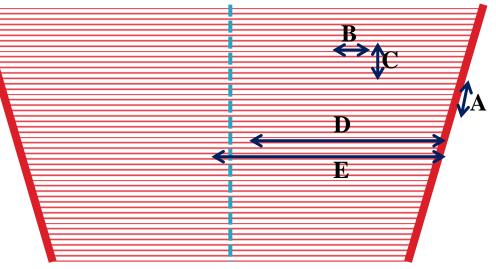
# Enlarged picture of resistive strip foil

10 mm



# **Resistivity check**

- We have no systematic way for resistivity test yet, so these results are based on rough measurements.
- However, we have check surface resistivity on several points for 8 foils as figure.
- The prove has about 2cm width.
- Distance between proves are, A,B,C: 1.5-2.5 cm, D: 30 cm, E: cross over a center line.
- "Inf" means more than  $50M\Omega$ .



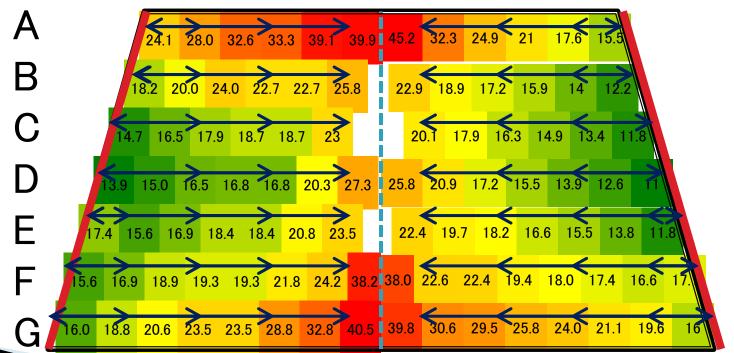
Unit: MΩ

No.	Α	В	С	D	E
1	1.4	4	15	6	Inf
2	2.7	2.2	15	9.5	Inf
3	1.5	2.2	13.1	8.3	Inf
4	2.8	1.5	11	6.6	Inf
5	2.2	1.8	10.5	6.3	Inf
6	1.9	2.1	10	6.9	Inf
7	2.5	2.3	10.6	7.4	Inf
8	2.4	2.5	12.3	7.3	Inf

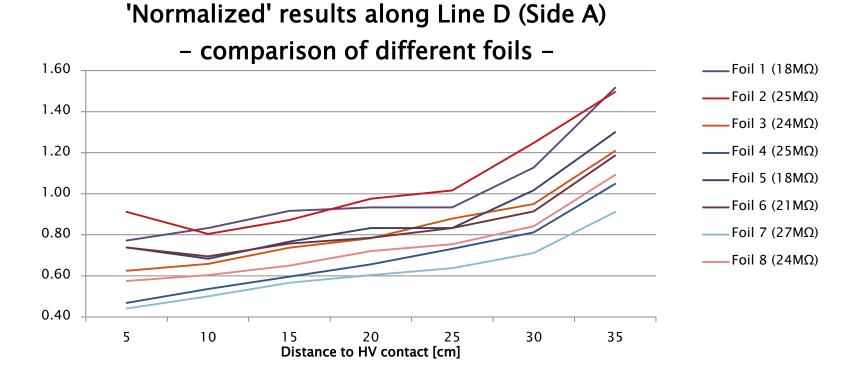
## **Resistivity check**

 Resistivity from edge to lattice point (5cm x 5cm) were measured (by Fabien Kuger).

Foil: No.1, Unit: MΩ



# **Comparison of different foils**



Variability of ~ 30% were found for different foils
 Reducing it is one of future issue

## With readout board

- 4 foils are attached to readout board successfully (at Rui's workshop)
  - For making quadruplet prototype (MSW)
  - Resistivity did not change after gluing
- Pillars will be formed soon



# Conclusion

- Sputtering technology is very promising for making MPGD resistive electrodes
  - Fine structure (~10µm)
  - Large area ( a few meter)
- Prototype of MicroMEGAS using sputtered resistive electrodes were produced and tested.
  - It works as same as conventional resistive strip MicroMEGAS
  - Gain curve, operation in HIP were tested. It's OK.
- Carbon sputtering process is improved for ATLAS MicroMEGAS
  - Appropriate resistivity ~  $500k\Omega/sq$  with thick (3600Å) sputtering.
  - Good mechanical/chemical properties
- Large resistive strip foils (0.5m x 1m) are produced for functional prototype (MSW).
  - Qualitative resistivity check is ok.
  - The foils are already put on the readout board.
  - No resistivity change found before/after foil gluing.